

10-Bit transparent latch; 3-state**74LVC841****FEATURES**

- Wide supply voltage range of 1.2 V to 3.6 V
- In accordance with JEDEC standard no. 8-1A.
- Inputs accept voltages upto 5.5 V
- CMOS low power consumption
- Direct interface with TTL levels
- Flow-through pin-out architecture
- Output drive capability 50 Ω transmission lines @ 85 °C

DESCRIPTION

The 74LVC841 is a low-power, low-voltage, Si-gate CMOS device and superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in a mixed 3.3 V/5 V environment.

The 74LVC841 is an 10-bit transparent latch featuring separate D-type inputs for each latch and 3-state outputs for bus oriented applications. A latch enable (LE) input and an output enable ($\overline{OE}$) input are common to all internal latches.

The '841' consists of ten transparent latches with 3-state true outputs. When LE is HIGH, data at the D_n inputs enters the latches. In this condition the latches are transparent, i.e. a latch output will change each time its corresponding D-input changes. When LE is LOW the latches store the information that was present at the D-inputs a set-up time preceding the HIGH-to-LOW transition of LE. When $\overline{OE}$ is LOW, the contents of the ten latches are available at the outputs. When $\overline{OE}$ is HIGH, the outputs go to the high impedance OFF-state. Operation of the $\overline{OE}$ input does not affect the state of the latches.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25\text{ }^{\circ}\text{C}$; $t_r = t_f \leq 2.5\text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t_{PHL}/t_{PLH}	propagation delay D_n to Q_n ; LE to Q_n	$C_L = 50\text{ pF}$ $V_{CC} = 3.3\text{ V}$	4.3 4.6	ns
C_i	input capacitance		5.0	pF
C_{PD}	power dissipation capacitance per latch	notes 1 and 2	23	pF

Notes to the quick reference data

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW):
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:
 f_i = input frequency in MHz; C_L = output load capacity in pF;
 f_o = output frequency in MHz; V_{CC} = supply voltage in V;
 $\Sigma (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.
2. The condition is $V_i = \text{GND to } V_{CC}$.

ORDERING INFORMATION

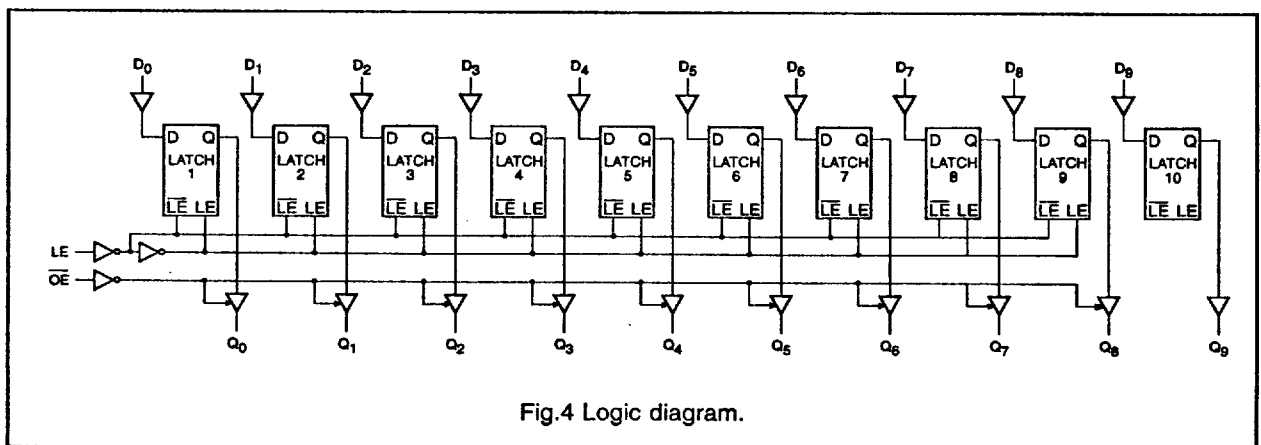
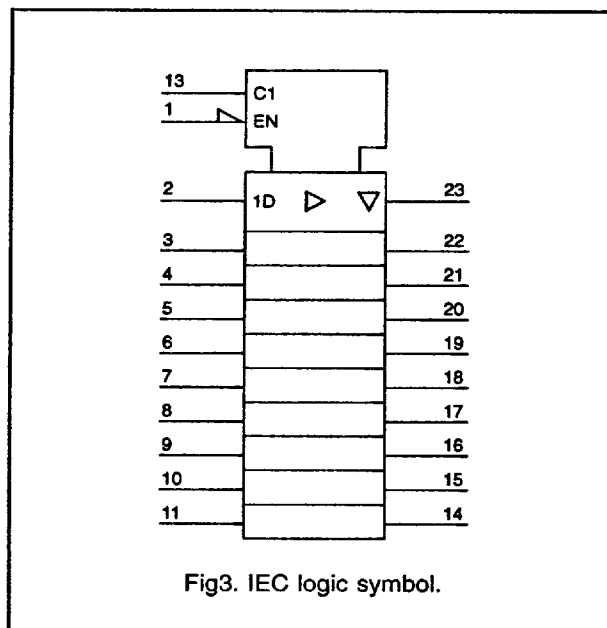
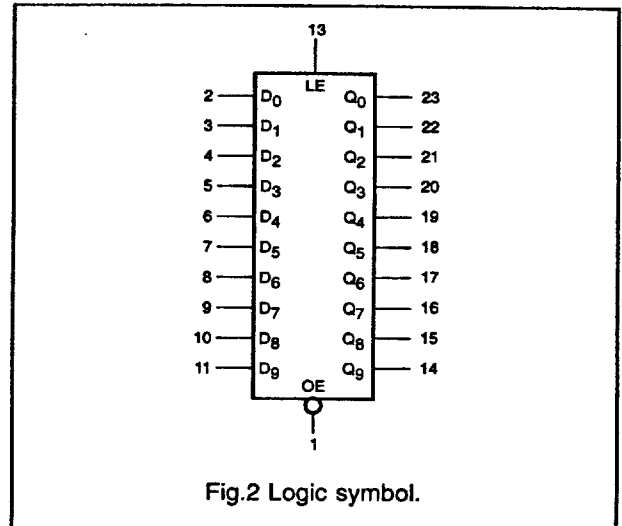
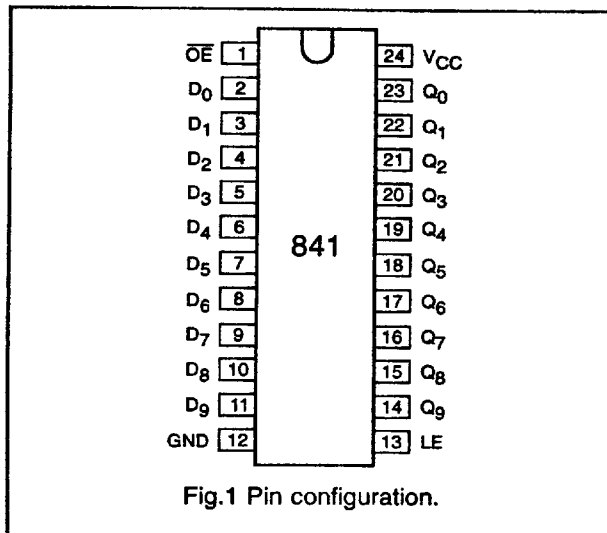
TYPE NUMBER	PACKAGES			
	PINS	PACKAGE	MATERIAL	CODE
74LVC841D	24	SO	plastic	SO24/SOT137
74LVC841DB	24	SSOP	plastic	SSOP24/SOT340
74LVC841PW	24	TSSOP	plastic	TSSOP24/SOT355

PINNING

PIN	SYMBOL	NAME AND FUNCTION
1	$\overline{OE}$	output enable input (active LOW)
2, 3, 4, 5, 6, 7, 8, 9, 10, 11	D_0 to D_9	data inputs
23, 22, 21, 20, 19, 18, 17, 16, 15, 14	Q_0 to Q_9	3-state latch outputs
12	GND	ground (0 V)
13	LE	latch enable input (active HIGH)
24	V_{CC}	positive supply voltage

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FUNCTION TABLE

OPERATING MODES	INPUTS			INTERNAL LATCHES	OUTPUTS Q ₀ to Q ₉
	$\overline{OE}$	LE	D _n		
enable and read register (transparent mode)	L L	H H	L H	L H	L H
latch and read register	L L	↓ ↓	l h	L H	L H
latch register and disable outputs	H H	X X	l h	L H	Z Z
hold	L	L	X	NC	NC

H = HIGH voltage level

h = HIGH voltage level one set-up time prior to the HIGH-to-LOW LE transition

L = LOW voltage level

l = LOW voltage level one set-up time prior to the HIGH-to-LOW LE transition

X = don't care

Z = high impedance OFF-state

NC = no change

DC CHARACTERISTICS FOR 74LVC841

For the DC characteristics see chapter "LVC family characteristics", section "Family specifications".

AC CHARACTERISTICS FOR 74LVC841

GND = 0 V; t_r = t_f ≤ 2.5 ns; C_L = 50 pF

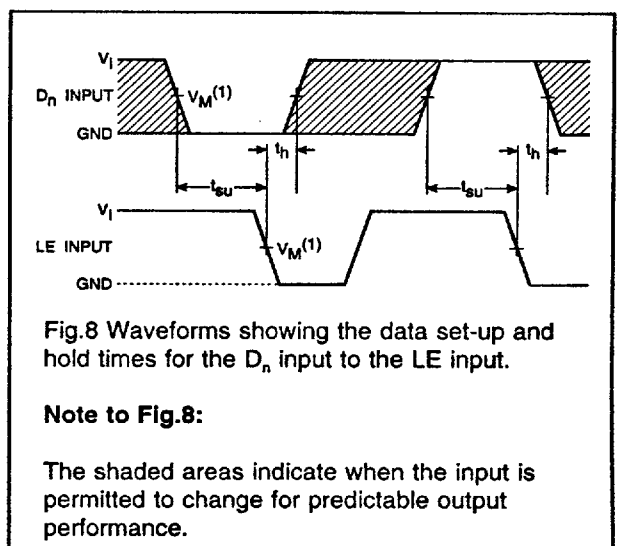
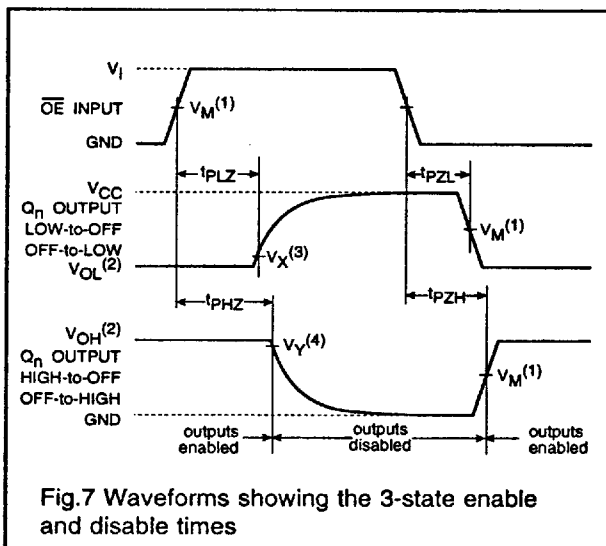
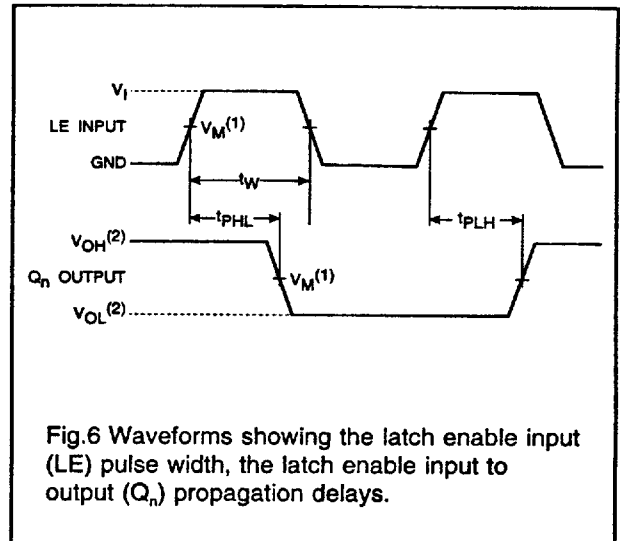
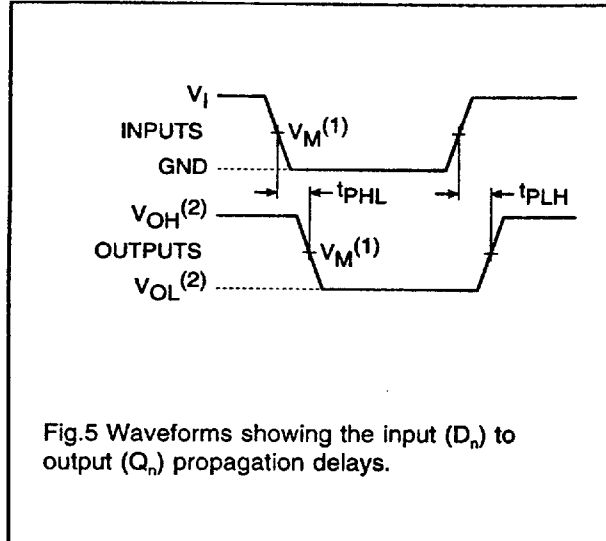
SYMBOL	PARAMETER	T _{amb} (°C)			UNIT	TEST CONDITIONS	
		-40 to +85				V _{cc} (V)	WAVEFORMS
		MIN.	TYP.	MAX.			
t _{PHL} /t _{PLH}	propagation delay D _n to Q _n	—	—	—	ns	1.2	Fig.5
		1.5	—	8.5		2.7	
		1.5	—	7.5		3.0 to 3.6	
t _{PHL} /t _{PLH}	propagation delay LE to Q _n	—	—	—	ns	1.2	Fig.6
		1.5	—	9.0		2.7	
		1.5	—	8.0		3.0 to 3.6	
t _{PZH} /t _{PZL}	3-state output enable time OE to Q _n	—	—	—	ns	1.2	Fig.7
		1.5	—	8.5		2.7	
		1.5	—	8.0		3.0 to 3.6	
t _{PHZ} /t _{PLZ}	3-state output disable time OE to Q _n	—	—	—	ns	1.2	Fig.7
		1.5	—	7.5		2.7	
		1.5	—	7.0		3.0 to 3.6	
t _W	LE pulse width HIGH	—	3.0	—	ns	2.7	Fig.8
		—	3.0*	—		3.0 to 3.6	
t _{su}	set-up time D _n to LE	1.0	0.2	—	ns	2.7	Fig.8
		1.0	0.2*	—		3.0 to 3.6	
t _h	hold time D _n to LE	1.0	0	—	ns	2.7	Fig.8
		1.0	0*	—		3.0 to 3.6	

Notes: All typical values are measured at T_{amb} = 25 °C.* Typical values are measured at V_{CC} = 3.3 V.

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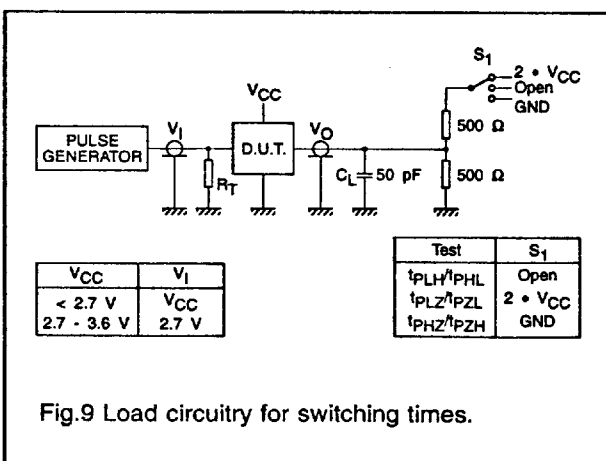
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AC WAVEFORMS



Note to Fig.8:

The shaded areas indicate when the input is permitted to change for predictable output performance.



- Notes:
- (1) $V_M = 1.5 \text{ V}$ at $V_{CC} \geq 2.7 \text{ V}$
 $V_M = 0.5 \cdot V_{CC}$ at $V_{CC} < 2.7 \text{ V}$
 - (2) V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load
 - (3) $V_X = V_{OL} + 0.3 \text{ V}$ at $V_{CC} \geq 2.7 \text{ V}$
 $V_X = V_{OL} + 0.1 \cdot V_{CC}$ at $V_{CC} < 2.7 \text{ V}$
 - (4) $V_Y = V_{OH} - 0.3 \text{ V}$ at $V_{CC} \geq 2.7 \text{ V}$
 $V_Y = V_{OH} - 0.1 \cdot V_{CC}$ at $V_{CC} < 2.7 \text{ V}$